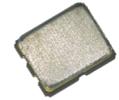


**CRYSTAL OSCILLATOR (Programmable)**  
**OUTPUT: CMOS**

 Product Number  
**SG-8201CJA: X1G005991xxxx16**  
**SG-8201CGA: X1G006281xxxx16**

# SG-8201CJA/CGA

- Frequency range : 1.2 MHz to 170 MHz
- Supply voltage : 1.62 V to 3.63 V
- Function : Output enable (OE/ $\overline{OE}$ ) or Standby ( $\overline{ST}$ / $\overline{ST}$ )
- Frequency tolerance, operating temperature:
  - $\pm 15 \times 10^{-6}$  (-40 °C to +105 °C)
  - $\pm 25 \times 10^{-6}$ ,  $\pm 50 \times 10^{-6}$  (-40 °C to +125 °C)
- PLL technology to enable setting any output frequency
- AEC-Q100 compliant


 SG-8201CJA  
 2.0 × 1.6 mm

 SG-8201CGA  
 2.5 × 2.0 mm

## Specifications (characteristics)

Item	Symbol	Specifications			Conditions/Remarks			
Supply voltage	$V_{CC}$	1.80 V Typ.	2.50 V Typ.	3.30 V Typ.				
		1.62 V to 1.98 V	2.25 V to 2.75 V	2.97 V to 3.63 V				
Output frequency range	$f_o$	1.2 MHz to 170 MHz						
Storage temperature	$T_{stg}$	-55 °C to +150 °C			Storage as single product.			
Operating temperature	$T_{use}$	H: -40 °C to +105 °C						
		J: -40 °C to +125 °C						
Frequency tolerance <sup>*1</sup>	$f_{tol}$	B: $\pm 15 \times 10^{-6}$			$T_{use} = -40 \text{ °C to } +105 \text{ °C}$			
		D: $\pm 25 \times 10^{-6}$			$T_{use} = -40 \text{ °C to } +125 \text{ °C}$			
		J: $\pm 50 \times 10^{-6}$			$T_{use} = -40 \text{ °C to } +125 \text{ °C}$			
Current consumption	$I_{CC}$	5.2 mA Typ.	5.4 mA Typ.	5.6 mA Typ.	1.2 MHz $\leq f_o \leq 25$ MHz	No load, Rise/Fall time: Default		
		7.0 mA Max.	7.2 mA Max.	7.5 mA Max.				
		5.4 mA Typ.	5.7 mA Typ.	6.1 mA Typ.	25 MHz $< f_o \leq 50$ MHz			
		7.3 mA Max.	7.6 mA Max.	8.1 mA Max.				
		5.7 mA Typ.	6.3 mA Typ.	7.0 mA Typ.	50 MHz $< f_o \leq 75$ MHz			
		7.7 mA Max.	8.2 mA Max.	9.1 mA Max.				
		6.2 mA Typ.	6.9 mA Typ.	7.9 mA Typ.	75 MHz $< f_o \leq 100$ MHz			
		8.2 mA Max.	9.1 mA Max.	10.4 mA Max.				
		6.9 mA Typ.	7.9 mA Typ.	9.1 mA Typ.	100 MHz $< f_o \leq 125$ MHz			
		9.4 mA Max.	10.7 mA Max.	12.4 mA Max.				
7.8 mA Typ.	9.2 mA Typ.	11.2 mA Typ.	125 MHz $< f_o \leq 170$ MHz					
10.4 mA Max.	12.4 mA Max.	15.0 mA Max.						
Output disable current	$I_{dis}$	5.0 mA Typ.	5.0 mA Typ.	5.1 mA Typ.	OE = GND, $\overline{OE} = V_{CC}$			
		7.2 mA Max.	7.3 mA Max.	7.4 mA Max.				
Standby current	$I_{std}$	0.3 $\mu$ A Typ.	0.3 $\mu$ A Typ.	0.5 $\mu$ A Typ.	$\overline{ST} = \text{GND}, \overline{ST} = V_{CC}$			
		15.0 $\mu$ A Max.	15.0 $\mu$ A Max.	15.0 $\mu$ A Max.				
Symmetry	SYM	45 % to 55 %			50 % $V_{CC}$ Level, $L_{CMOS} \leq 15$ pF			
Output voltage (DC characteristics)	$V_{OH}$	90 % $V_{CC}$ Min.			Rise/Fall time			
					Default 'A' Option <sup>*2</sup>	Other Options	$I_{OH}$	$I_{OL}$
	$V_{OL}$	10 % $V_{CC}$ Max.			fo > 125 MHz	B: Faster	-2.0 mA	2.0 mA
					75 MHz $< f_o \leq 125$ MHz	C: Fast	-1.0 mA	1.0 mA
				50 MHz $< f_o \leq 75$ MHz	D: Slow	-0.5 mA	0.5 mA	
				fo $\leq 50$ MHz	E: Slower	-0.2 mA	0.2 mA	
Output load condition	$L_{CMOS}$	15 pF Max.						
Input voltage	$V_{IH}$	70 % $V_{CC}$ Min.			Pin 1			
	$V_{IL}$	30 % $V_{CC}$ Max.						
Rise/Fall time	tr/ff	-			Default 'A' Option <sup>*2</sup>	Other Options	20 % - 80 % $V_{CC}$ , $L_{CMOS} = 15$ pF	
					fo > 125 MHz	B: Faster		
					75 MHz $< f_o \leq 125$ MHz	C: Fast		
					50 MHz $< f_o \leq 75$ MHz	D: Slow		
				fo $\leq 50$ MHz	E: Slower			
Output disable time (OE)	tstp_oe	1 $\mu$ s Max.			Measured from the time OE or $\overline{ST}$ pin crosses 30 % $V_{CC}$			
Output disable time (ST)	tstp_st				or measured from the time OE or ST pin crosses 70 % $V_{CC}$			
Output enable time (OE)	tsta_oe	100 ns + 2 clock cycle Max.			Measured from the time OE pin crosses 70 % $V_{CC}$			
Output enable time (ST)	tsta_st				or measured from the time $\overline{OE}$ pin crosses 30 % $V_{CC}$			
Start-up time	t_str	3 ms Max.			Measured from the time $V_{CC}$ reaches its rated minimum value, 1.62 V			
Phase Jitter	$t_{PJ}$	1.2 ps Typ.			fo = 25 MHz, Offset frequency: 12 kHz to 5 MHz			
		1.2 ps Typ.			fo = 50 MHz, Offset frequency: 12 kHz to 20 MHz			
		1.2 ps Typ.			fo = 75 MHz, Offset frequency: 12 kHz to 20 MHz			
		1.2 ps Typ.			fo = 100 MHz, Offset frequency: 12 kHz to 20 MHz			
		1.1 ps Typ.			fo = 125 MHz, Offset frequency: 12 kHz to 20 MHz			
		1.4 ps Typ.			fo = 150 MHz, Offset frequency: 12 kHz to 20 MHz			
						fo = 170 MHz, Offset frequency: 12 kHz to 20 MHz		
Frequency aging	f_age	This is included in frequency tolerance specification.			+25 °C, first year			

\*1 Frequency tolerance includes initial frequency tolerance, temperature variation, supply voltage variation, reflow drift, load drift and aging (+25 °C, 1 year).

\*2 Default 'A' Rise/Fall time and  $I_{OH}/I_{OL}$  are dependent on programmed frequency.

## Pin description

Pin	Name	I/O type	Function	
1	OE	Input	Output Enable	High <sup>*1</sup> or Open: Specified frequency output from OUT pin Low: OUT pin is low (pull down with 500 kΩ), only output driver is disabled.
	$\overline{\text{OE}}$	Input	Output Enable	Low <sup>*2</sup> or Open: Specified frequency output from OUT pin High: OUT pin is low (pull down with 500 kΩ), only output driver is disabled.
	$\overline{\text{ST}}$	Input	Standby	High <sup>*1*3</sup> : Specified frequency output from OUT pin Low: OUT pin is low (pull down with 500 kΩ), Device goes to standby mode. Supply current reduces to the least as I <sub>std</sub> .
	ST	Input	Standby	Low <sup>*2*3</sup> : Specified frequency output from OUT pin High: OUT pin is low (pull down with 500 kΩ), Device goes to standby mode. Supply current reduces to the least as I <sub>std</sub> .
2	GND	Power	Ground	
3	OUT	Output	Clock output	
4	V <sub>CC</sub>	Power	Power supply	

\*1 If fixing it at High, please connect to V<sub>CC</sub> directly.

\*2 If fixing it at Low, please connect to GND directly.

\*3 If necessary to use Open, please select Output Enable function.

## Product Name

SG-8201CJA 170.000000MHz T D J P A  
a b c d e f g h

b: Package type

CJ	2.0 mm × 1.6 mm
CG	2.5 mm × 2.0 mm

e: Frequency tolerance / f: Operating temperature

BH	±15 × 10 <sup>-6</sup> / -40 °C to +105 °C
DJ	±25 × 10 <sup>-6</sup> / -40 °C to +125 °C
JJ	±50 × 10 <sup>-6</sup> / -40 °C to +125 °C

a: Model b: Package type

c: Frequency d: Supply voltage (T: 1.8 V to 3.3 V Typ.)

e: Frequency tolerance f: Operating temperature

g: Function h: Rise/Fall time

g: Function

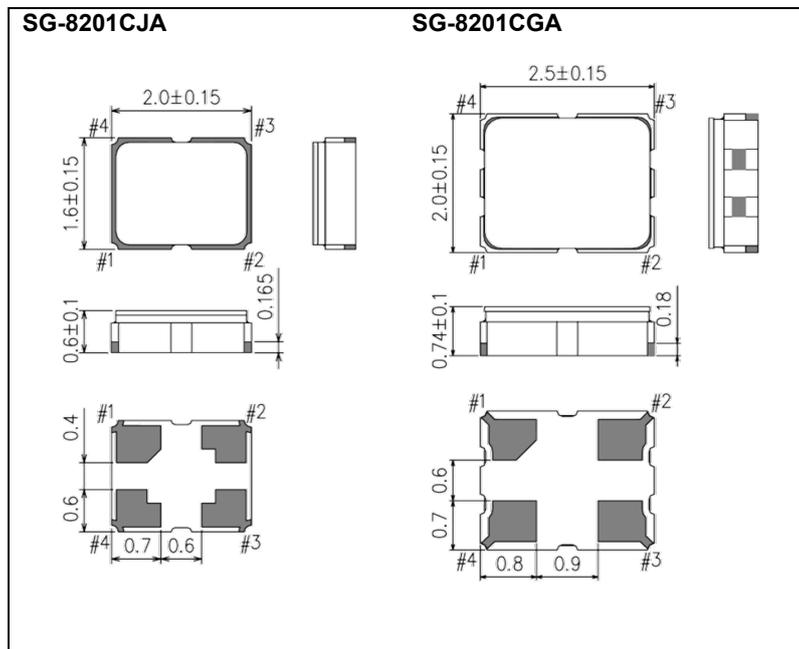
P	Output Enable (OE)
Q	Output Enable ( $\overline{\text{OE}}$ )
S	Standby (ST)
T	Standby ( $\overline{\text{ST}}$ )

h: Rise/Fall time

A	Default
B	Faster
C	Fast
D	Slow
E	Slower

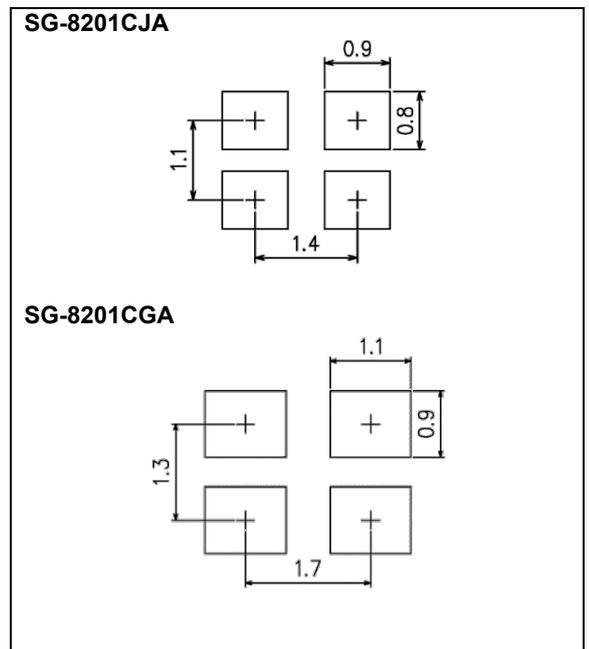
## External dimensions

(Unit: mm)



## Footprint (Recommended)

(Unit: mm)



## Notes:

In order to achieve optimum jitter performance, the 0.01 μF to 0.1 μF capacitor between V<sub>CC</sub> and GND should be placed. It is also recommended that the capacitors are placed on the device side of the PCB, as close to the device as possible and connected together with short wiring pattern.

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	<p>► Complies with EU RoHS directive.          *About the products without the Pb-free mark.          Contains Pb in products exempted by EU RoHS directive.          (Contains Pb in sealing glass, high melting temperature type solder or other.)</p>
	<p>► Designed for automotive general equipment.</p>
	<p>► Designed for automotive applications related to driving and safety.</p>

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